NSN 5962-01-195-1243

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N/a



View Online at https://aerobasegroup.com/nsn/5962-01-195-1243

view Offiline at https://aerobasegroup.com/nish/0302-01-130-1240
Body Length:
1.260 inches
Body Width:
Between 0.350 inches and 0.390 inches
Body Height:
0.210 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
3-state output and monolithic and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Case Outline Source And Designator:
D-7 mil-m-38510
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Special Features:
Bright tin plating prohibited
Precious Material And Location:
Terminal surfaces optional gold
Precious Material:
Gold
Test Data Document:
82577-932775 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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